

TECHNICAL DATA DATA SHEET 4614, REV.A

HERMETIC POWER SCHOTTKY RECTIFIER

(SINGLE / DUAL)

DESCRIPTION: A 15 VOLT, 7.5 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC SMD-1 PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25$ °C UNLESS OTHERWISE SPECIFIED.

| RATING | | MAX. | UNITS |
|--|------------------|-----------------|-------|
| PEAK INVERSE VOLTAGE | PIV | 15 | Volts |
| MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ T_C =70 $^{\circ}$ C) (Single) | | 7.5 | Amps |
| MAXIMUM DC OUTPUT CURRENT With Cathode Maintained (@ $T_C=70$ $^{\circ}$ C) (Common Cathode) | | 15 | Amps |
| MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t = 8.3ms, Sine) | I _{FSM} | 140 | Amps |
| MAXIMUM JUNCTION CAPACITANCE (V _r =5V) | C _T | 600 | pF |
| MAXIMUM THERMAL RESISTANCE | $R_{	heta JC}$ | 1.21 | °C/W |
| MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE | | -65 to + 100 | °C |

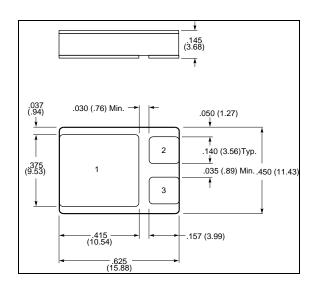
ELECTRICAL CHARACTERISTICS

| CHARACTERISTIC | | | | |
|--|-------------------------|----------------|------|-------|
| MAXIMUM FORWARD VOLTAGE DROP, Pulsed (I _f = 7.5 Amps) | | | | |
| | T _J = 25 °C | V_{f} | 0.45 | Volts |
| | T _J = 125 °C | | 0.41 | |
| MAXIMUM REVERSE CURRENT (I _r @ 15 V PIV) | | | | |
| | T _J = 25 °C | l _r | 3.5 | mA |
| | T _J = 125 °C | | 170 | |

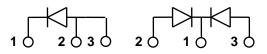


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MECHANICAL DIMENSIONS: In Inches / mm



SINGLE COMMON CATHODE



SMD-1

PINOUT TABLE

| DEVICE TYPE | PIN 1 | PIN 2 | PIN 3 |
|------------------------------|----------------|---------|---------|
| SINGLE RECTIFIER - SHD119168 | CATHODE | ANODE | ANODE |
| COMMON CATHODE - SHD119168P | COMMON CATHODE | ANODE 1 | ANODE 2 |

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